NSN 5961-01-475-7135

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-475-7135 **Inclosure Material:** Metal **Overall Length:** 28.500 millimeters **Terminal Length:** 25.300 millimeters **Overall Height:** 21.000 millimeters **Overall Width:** 28.500 millimeters **End Application:** E/ifscm navy equipment **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage and 1600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 36.00 amperes peak forward surge current major **Power Rating Per Characteristic:** 1.1 kilowatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 5 quick disconnect, male Shelf Life: N/a **Unit Of Measure: Demilitarization:** No